

RT1P151X SERIES

〈Transistor〉

Transistor With Resistor
For Switching Application
Silicon PNP Epitaxial Type

DESCRIPTION

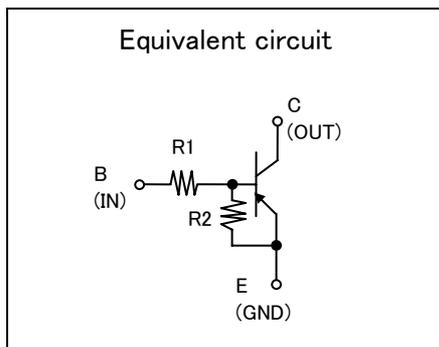
RT1P151X is a one chip transistor with built-in bias resistor, NPN type is RT1N151X.

FEATURE

• Built-in bias resistor (R1=100kΩ, R2=100kΩ).

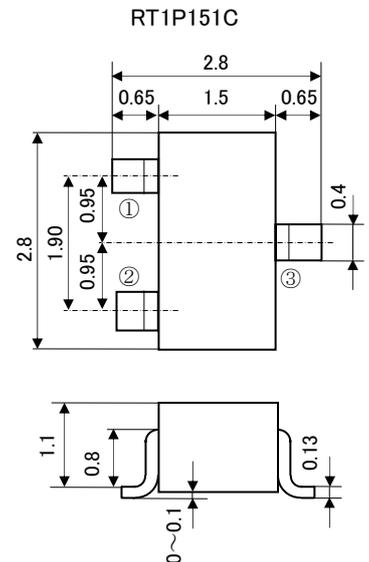
APPLICATION

. Inverted circuit, switching circuit, interface circuit, driver circuit.



OUTLINE DRAWING

UNIT : mm



JEITA: SC-59

JEDEC: Similar to TO-236

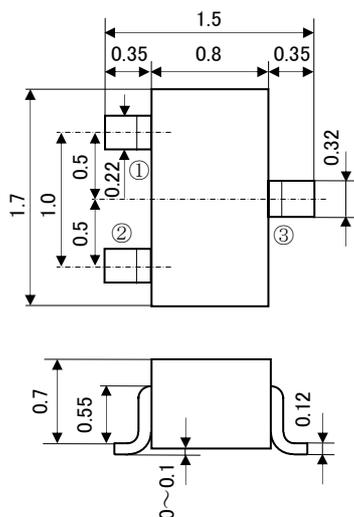
Terminal Connector

①: Base

②: Emitter

③: Collector

RT1P151U



JEITA: SC-75A

JEDEC: —

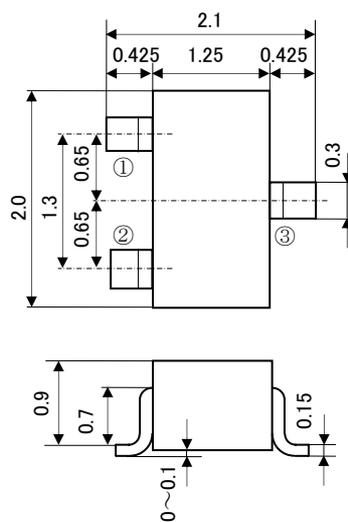
Terminal Connector

①: Base

②: Emitter

③: Collector

RT1P151M



JEITA: SC-70

JEDEC: —

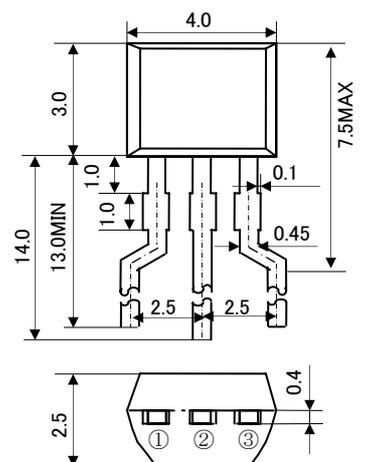
Terminal Connector

①: Base

②: Emitter

③: Collector

RT1P151S



JEITA: —

JEDEC: —

Terminal Connector

①: Emitter

②: Collector

③: Base

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MARKING

RT1P151C RT1P151M RT1P151U	RT1P151S

MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING				UNIT
		RT1P151U	RT1P151M	RT1P151C	RT1P151S	
V _{CBO}	Collector to Base voltage	-50				V
V _{EBO}	Emitter to Base voltage	-10				V
V _{CEO}	Collector to Emitter voltage	-50				V
V _{IN}	Input voltage	-40				V
I _C	Collector current	-100				mA
I _{CM}	Peak Collector current	-200				mA
P _C	Collector dissipation(Ta=25°C)	150	200	450	mW	
T _j	Junction temperature	+150				°C
T _{stg}	Storage temperature	-55~+150				°C

ELECTRICAL CHARACTERISTICS (Ta=25°C)

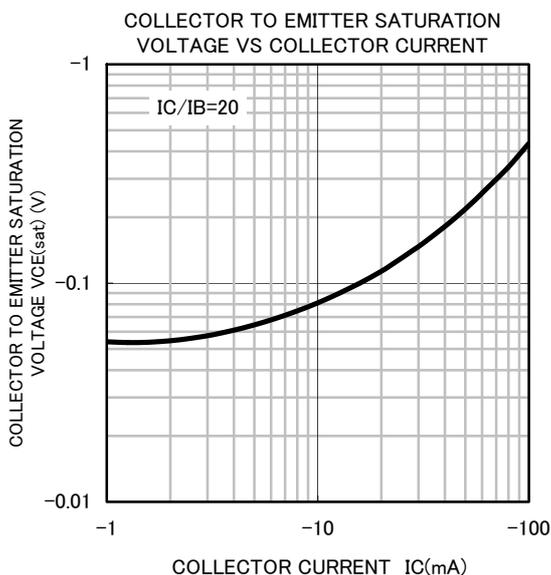
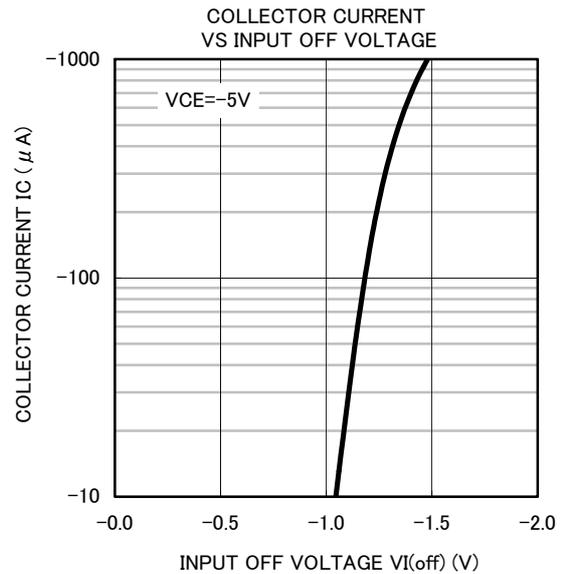
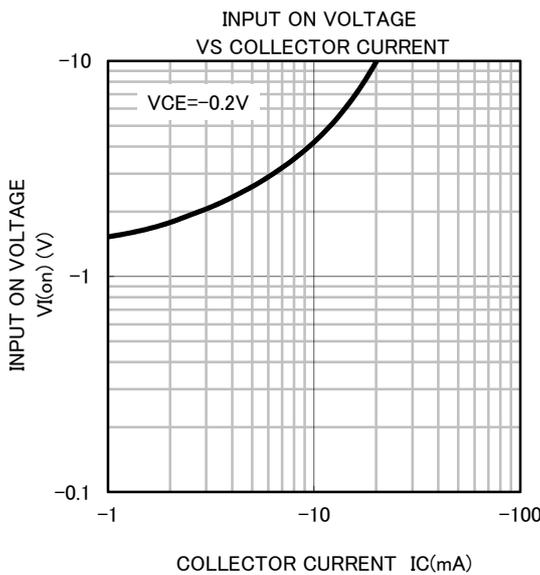
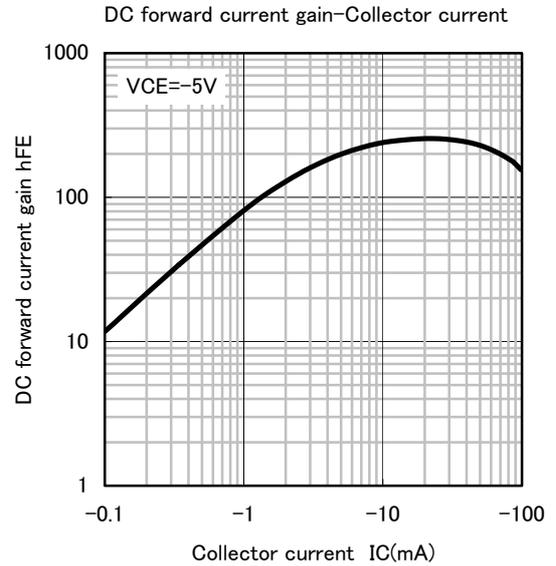
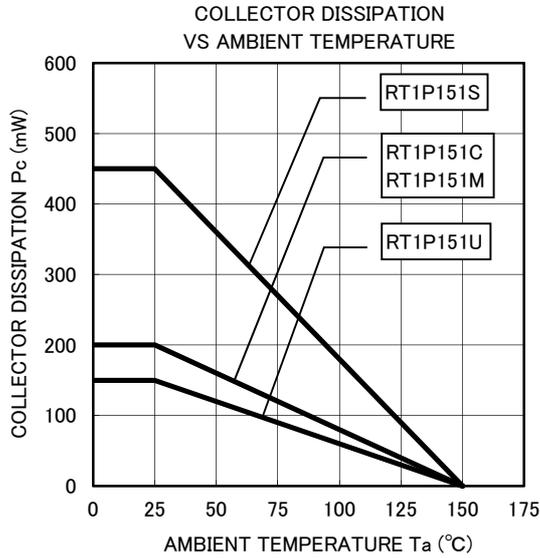
SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
			MIN	TYP	MAX	
V _{(BR)CEO}	C to E break down voltage	I _C = -100 μA, R _{BE} = ∞	-50	—	—	V
I _{CBO}	Collector cut off current	V _{CB} = -50V, I _E = 0	—	—	-0.1	μA
I _{EBO}	Emitter cut off current	V _{EB} = -5V, I _C = 0	-18.8	-25	-36.3	μA
h _{FE}	DC forward current gain	V _{CE} = -5V, I _C = -5mA	82	—	—	—
V _{CE(sat)}	C to E saturation voltage	I _C = -5mA, I _B = -0.25mA	—	-0.1	-0.3	V
V _{I(ON)}	Input on voltage	V _{CE} = -0.2V, I _C = -5mA	—	-2.4	-8.8	V
V _{I(OFF)}	Input off voltage	V _{CE} = -5V, I _C = -100 μA	-0.8	-1.1	—	V
R ₁	Input resistor	—	70	100	130	kΩ
R ₂ /R ₁	Resistor ratio	—	0.8	1.0	1.2	—
f _T	Gain band width product	V _{CE} = -6V, I _E = 10mA	—	150	—	MHz

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<Transistor>

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TYPICAL CHARACTERISTICS (Ta=25°C)





Keep safety first in your circuit designs!

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